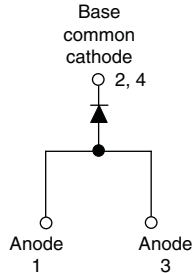


Fast Soft Recovery Rectifier Diode, 80 A



TO-247AC



FEATURES/DESCRIPTION

The 80EPF..PbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.



RoHS* COMPLIANT

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level and lead (Pb)-free.

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

PRODUCT SUMMARY

V_F at 40 A	< 1.2 V
t_{rr}	90 ns
V_{RRM}	1000/1200 V

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	TEST CONDITIONS	VALUES	UNITS
V_{RRM}		1000/1200	V
$I_{F(AV)}$	Sinusoidal waveform	80	A
I_{FSM}		1100	
t_{rr}	1 A, - 100 A/ μ s	90	ns
V_F	40 A, $T_J = 25^\circ\text{C}$	1.2	V
T_J		- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 $^\circ\text{C}$ mA
80EPF10PbF	1000	1100	12
80EPF12PbF	1200	1300	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 92^\circ\text{C}$, 180 $^\circ$ conduction half sine wave	80	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	1100	
		10 ms sine pulse, no voltage reapplied	1250	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	5000	A^2s
		10 ms sine pulse, no voltage reapplied	7000	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	70 000	$\text{A}^2\sqrt{\text{s}}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

80EPF..PbF Soft Recovery Series

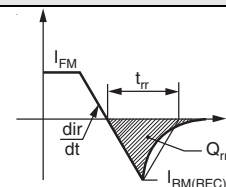


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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	80 A, $T_J = 25\text{ }^\circ\text{C}$		1.35	V
Forward slope resistance	r_t	$T_J = 150\text{ }^\circ\text{C}$		4.03	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$			0.87	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		12	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 80 Apk 25 A/ μs 25 $^\circ\text{C}$	480	ns
Reverse recovery current	I_{rr}		7.1	A
Reverse recovery charge	Q_{rr}		2.1	μC
Snap factor	S		0.5	



THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 40 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.35	$^\circ\text{C/W}$
Maximum thermal resistance, junction to ambient	R_{thJA}		40	
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AC (JEDEC)	80EPF10	
			80EPF12	



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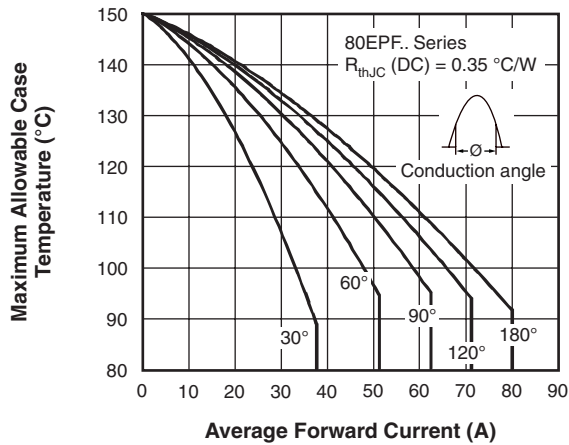


Fig. 1 - Current Rating Characteristics

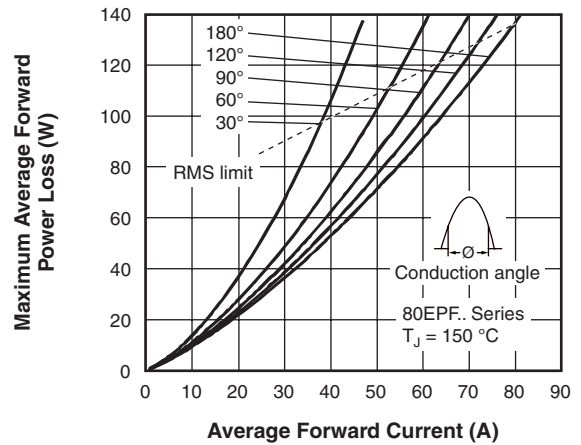


Fig. 4 - Forward Power Loss Characteristics

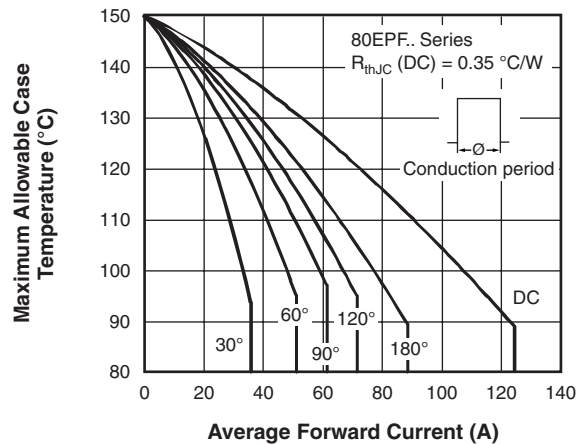


Fig. 2 - Current Rating Characteristics

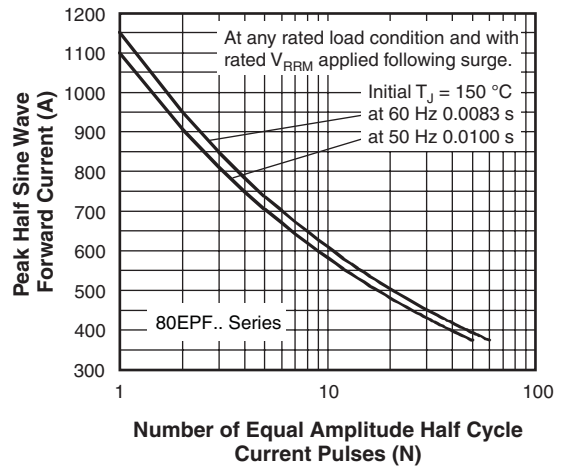


Fig. 5 - Maximum Non-Repetitive Surge Current

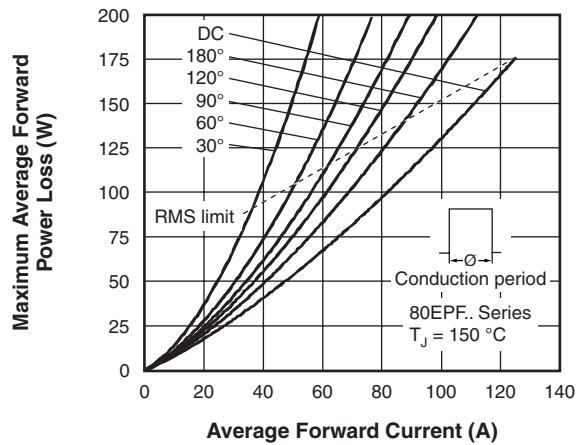


Fig. 3 - Forward Power Loss Characteristics

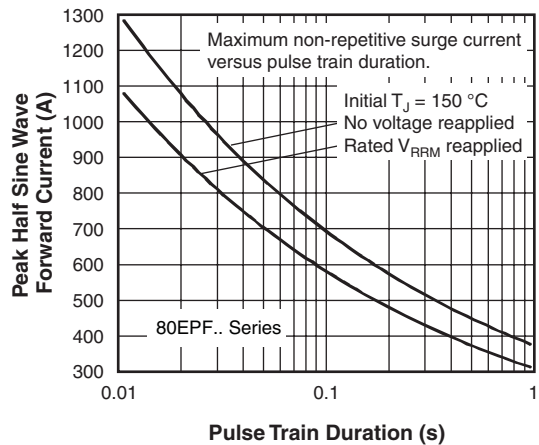


Fig. 6 - Maximum Non-Repetitive Surge Current

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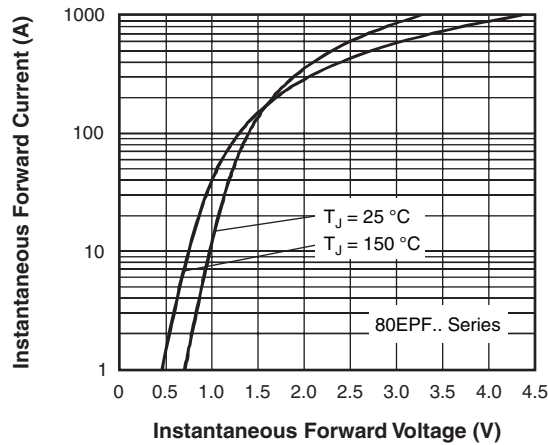


Fig. 7 - Forward Voltage Drop Characteristics

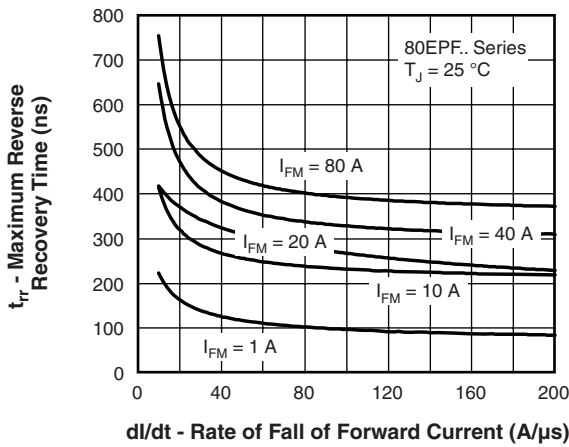


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ °C}$

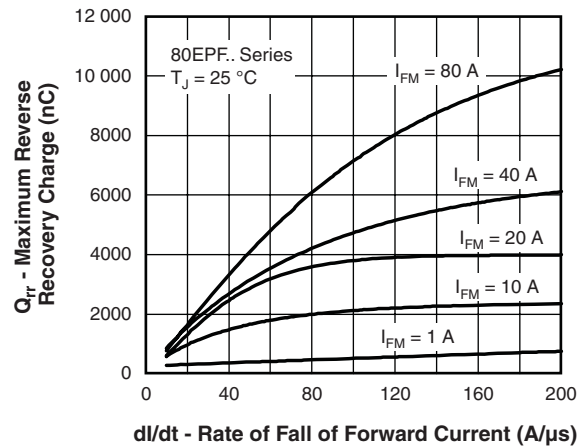


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ °C}$

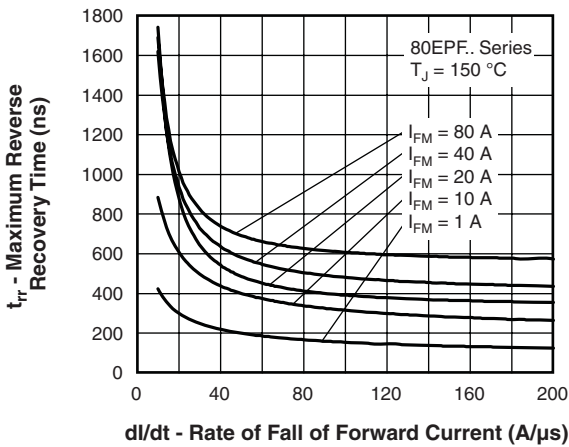


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ °C}$

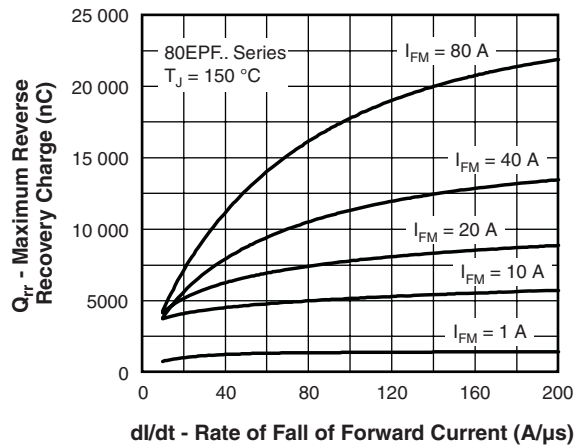


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ °C}$



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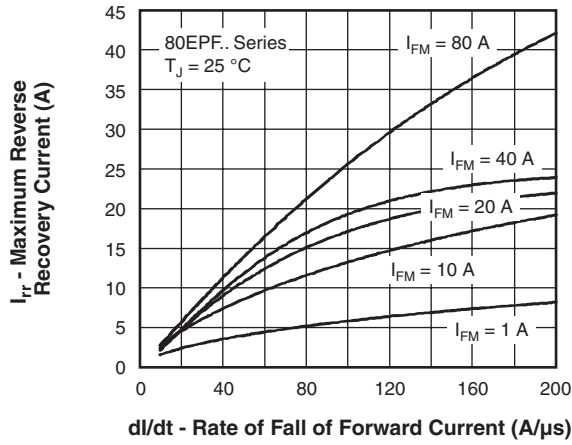


Fig. 12 - Recovery Current Characteristics, $T_J = 25\text{ }^\circ\text{C}$

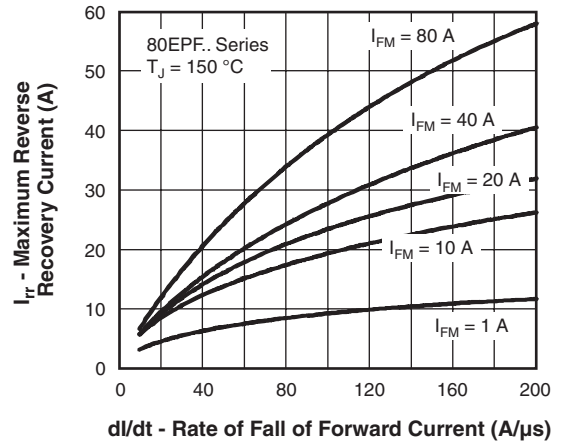


Fig. 13 - Recovery Current Characteristics, $T_J = 150\text{ }^\circ\text{C}$

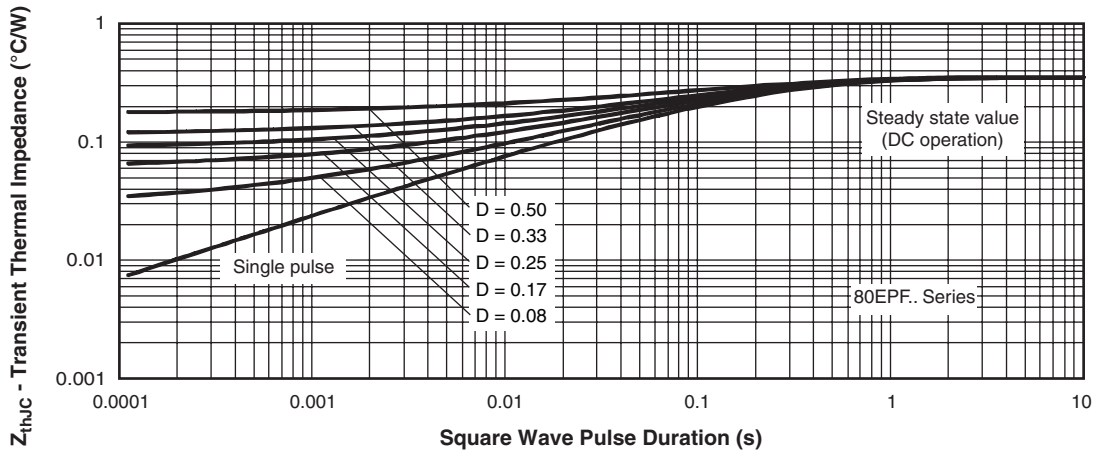


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

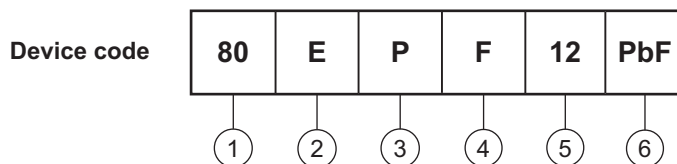
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ORDERING INFORMATION TABLE



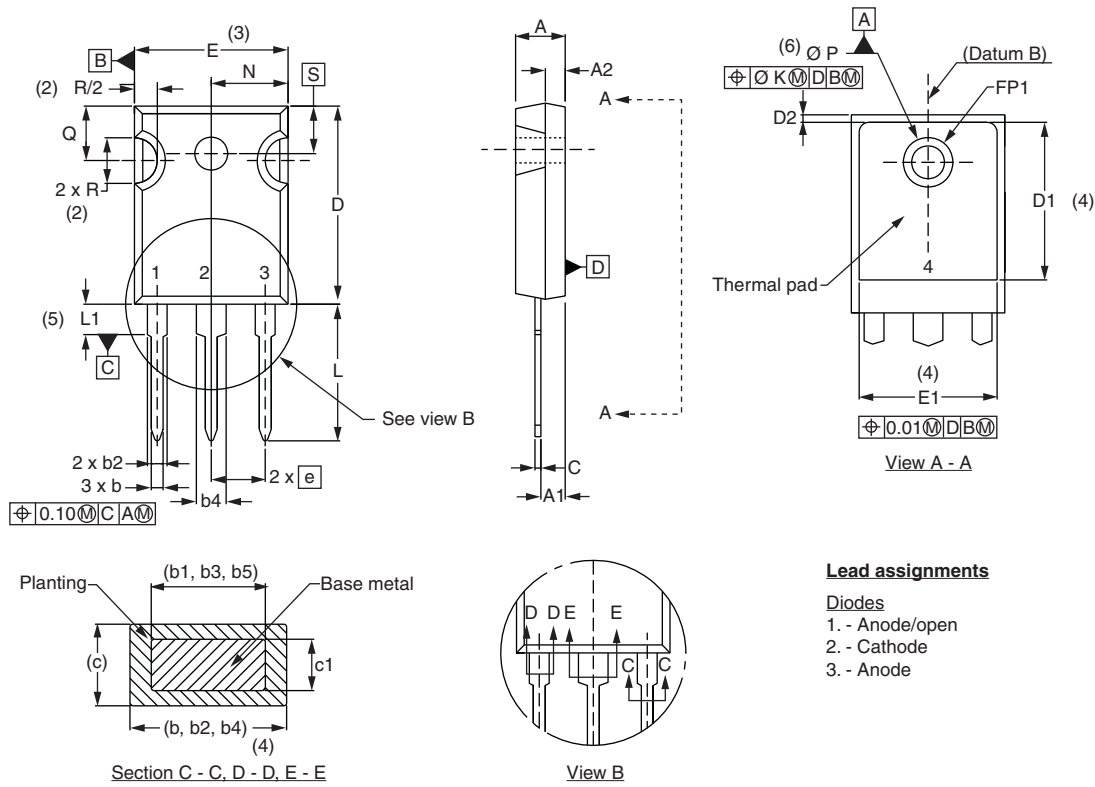
- 1** - Current rating (80 = 80 A)
- 2** - Circuit configuration:
E = Single diode
- 3** - Package:
P = TO-247AC
- 4** - Type of silicon:
F = Fast diode
- 5** - Voltage code x 100 = V_{RRM}
- 6** -
 - None = Standard production
 - PbF = Lead (Pb)-free

10 = 1000 V
12 = 1200 V

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95223
Part marking information	http://www.vishay.com/doc?95226



DIMENSIONS in millimeters and inches



Lead assignments

- Diodes
 1. - Anode/open
 2. - Cathode
 3. - Anode

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209		D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098		E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055		e	5.46 BSC		0.215 BSC		
b1	0.99	1.35	0.039	0.053		FK	2.54		0.010		
b2	1.65	2.39	0.065	0.094		L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		N	7.62 BSC		0.3		
b5	2.59	3.38	0.102	0.133		ΦP	3.56	3.66	0.14	0.144	
c	0.38	0.86	0.015	0.034		ΦP1	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	1.78	0.216	
D1	13.08	-	0.515	-	4	S	5.51 BSC		0.217 BSC		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



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